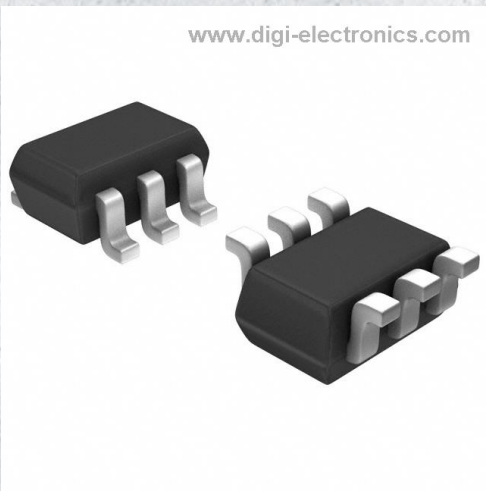
BCR135SE6327BTSA1 Datasheet



https://www.DiGi-Electronics.com

DiGi Electronics Part Number	BCR135SE6327BTSA1-DG
Manufacturer	Infineon Technologies
Manufacturer Product Number	BCR135SE6327BTSA1
Description	TRANS 2NPN PREBIAS 0.25W SOT363
Detailed Description	Pre-Biased Bipolar Transistor (BJT) 2 NPN - Pre-Biased (Dual) 50V 100mA 150MHz 250mW Surface Mount PG-SOT363-PO

Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

Purchase and inquiry

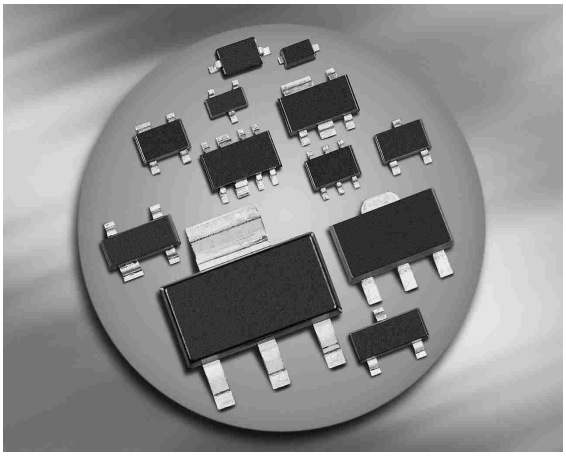
Manufacturer Product Number:	Manufacturer:
BCR135SE6327BTSA1	Infineon Technologies
Series:	Product Status:
-	Obsolete
Transistor Type:	Current - Collector (Ic) (Max):
2 NPN - Pre-Biased (Dual)	100mA
Voltage - Collector Emitter Breakdown (Max):	Resistor - Base (R1):
50V	10kOhms
Resistor - Emitter Base (R2):	DC Current Gain (hFE) (Min) @ Ic, Vce:
47kOhms	70 @ 5mA, 5V
Vce Saturation (Max) @ Ib, Ic:	Current - Collector Cutoff (Max):
300mV @ 500µA, 10mA	-
Frequency - Transition:	Power - Max:
150MHz	250mW
Mounting Type:	Package / Case:
Surface Mount	6-VSSOP, SC-88, SOT-363
Supplier Device Package:	Base Product Number:
PG-SOT363-PO	BCR135S

Environmental & Export classification

Moisture Sensitivity Level (MSL):	REACH Status:
1 (Unlimited)	REACH Unaffected
ECCN:	HTSUS:
EAR99	8541.21.0095

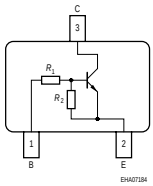
BCR135...

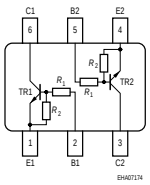
NPN Silicon Digital Transistor



- Switching circuit, inverter, interface circuit driver circuit
- Built in bias resistor (R_1=10 kΩ, R_2=47 kΩ)
- BCR135S: Two internally isolated transistors with good matching in one multichip package
- BCR135S: For orientation in reel see package information below
- Pb-free (RoHS compliant) package
- Qualified according AEC Q101

BCR135 **BCR135S**
BCR135W





Type	Marking	Pin Configuration						Package
BCR135	WJs	1=B	2=E	3=C	-	-	-	SOT23
BCR135S	WJs	1=E1	2=B1	3=C2	4=E2	5=B2	6=C1	SOT363
BCR135W	WJs	1=B	2=E	3=C	-	-	-	SOT323

Maximum Ratings

Parameter	Symbol	Value	Unit
Collector-emitter voltage	V_{CEO}	50	V
Collector-base voltage	V_{CBO}	50	
Input forward voltage	$V_{i(fwd)}$	40	
Input reverse voltage	$V_{i(rev)}$	6	
Collector current	I_C	100	mA
Total power dissipation	P_{tot}		mW
BCR135, $T_S \leq 102°C$		200	
BCR135S, $T_S \leq 115°C$		250	
BCR135W, $T_S \leq 124°C$		250	
Junction temperature	T_j	150	°C
Storage temperature	T_{stg}	-65 ... 150	

Thermal Resistance

Parameter	Symbol	Value	Unit
Junction - soldering point[1)]	R_{thJS}		K/W
BCR135		≤ 240	
BCR135S		≤ 140	
BCR135W		≤ 105	

[1]For calculation of R_{thJA} please refer to Application Note AN077 (Thermal Resistance Calculation)

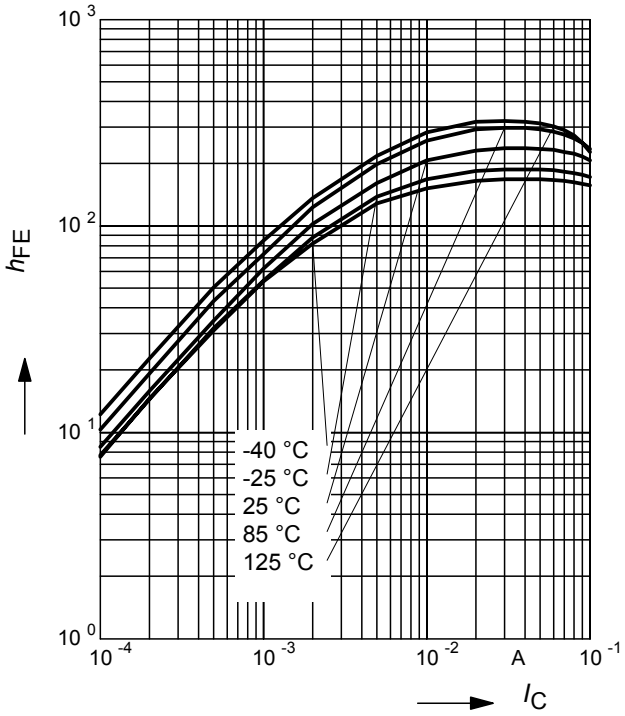
Electrical Characteristics at T_A = 25°C, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics					
Collector-emitter breakdown voltage I_C = 100 µA, I_B = 0	$V_{(BR)CEO}$	50	-	-	V
Collector-base breakdown voltage I_C = 10 µA, I_E = 0	$V_{(BR)CBO}$	50	-	-	
Collector-base cutoff current V_{CB} = 40 V, I_E = 0	I_{CBO}	-	-	100	nA
Emitter-base cutoff current V_{EB} = 6 V, I_C = 0	I_{EBO}	-	-	167	µA
DC current gain[1)] I_C = 5 mA, V_{CE} = 5 V	h_{FE}	70	-	-	-
Collector-emitter saturation voltage[1)] I_C = 10 mA, I_B = 0.5 mA	V_{CEsat}	-	-	0.3	V
Input off voltage I_C = 100 µA, V_{CE} = 5 V	$V_{i(off)}$	0.5	-	1	
Input on voltage I_C = 2 mA, V_{CE} = 0.3 V	$V_{i(on)}$	0.5	-	1.4	
Input resistor	R_1	7	10	13	kΩ
Resistor ratio	R_1/R_2	0.19	0.21	0.24	-
AC Characteristics					
Transition frequency I_C = 10 mA, V_{CE} = 5 V, f = 100 MHz	f_T	-	150	-	MHz
Collector-base capacitance V_{CB} = 10 V, f = 1 MHz	C_{cb}	-	3	-	pF

[1]Pulse test: t < 300µs; D < 2%

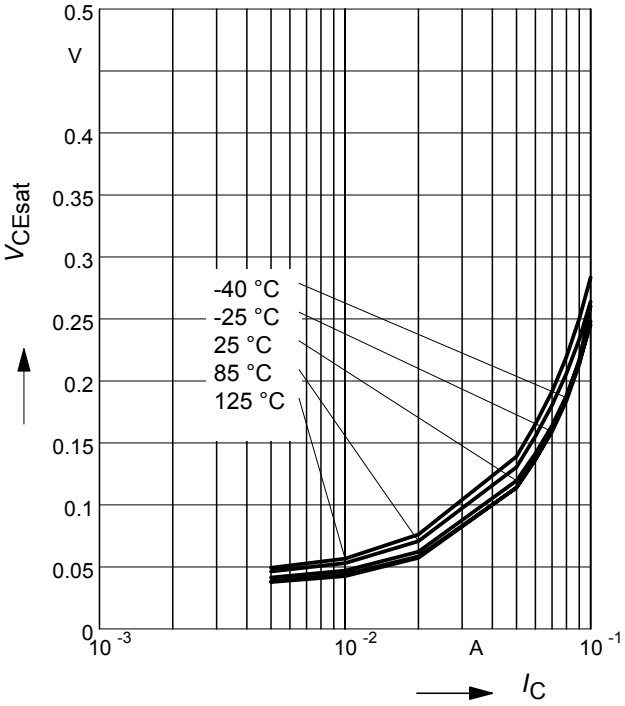
DC current gain h_{FE} = $f(I_C)$

V_{CE} = 5V (common emitter configuration)



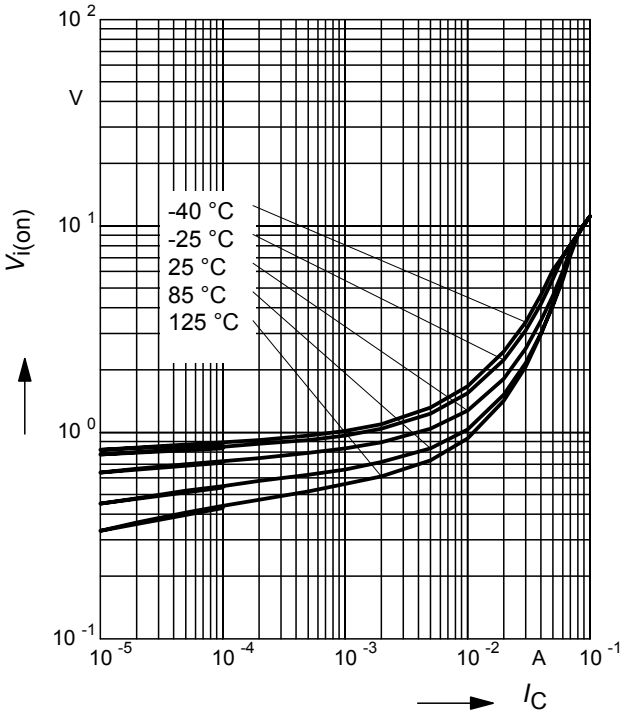
Collector-emitter saturation voltage

V_{CEsat} = $f(I_C)$, I_C/I_B = 20



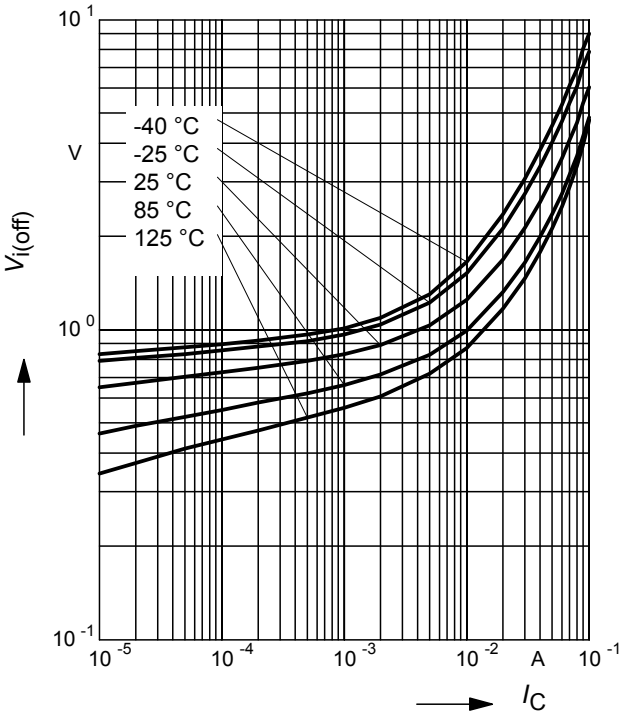
Input on Voltage $V_{i(on)}$ = $f(I_C)$

V_{CE} = 0.3V (common emitter configuration)

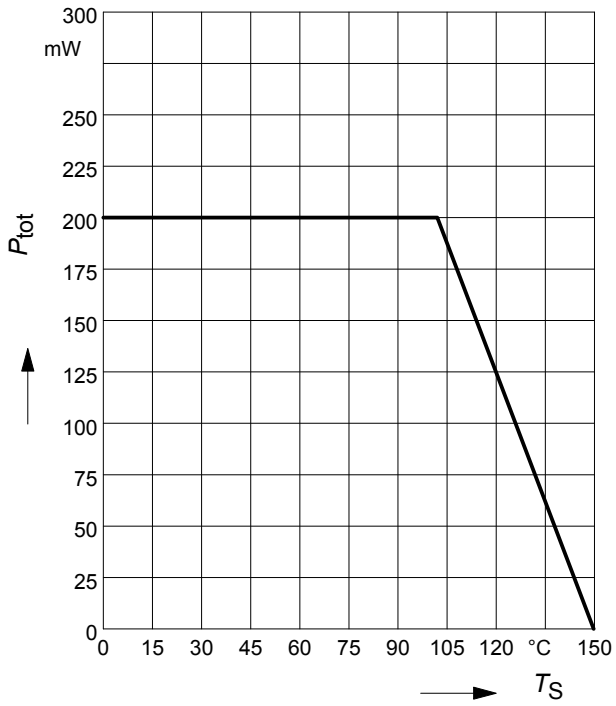


Input off voltage $V_{i(off)}$ = $f(I_C)$

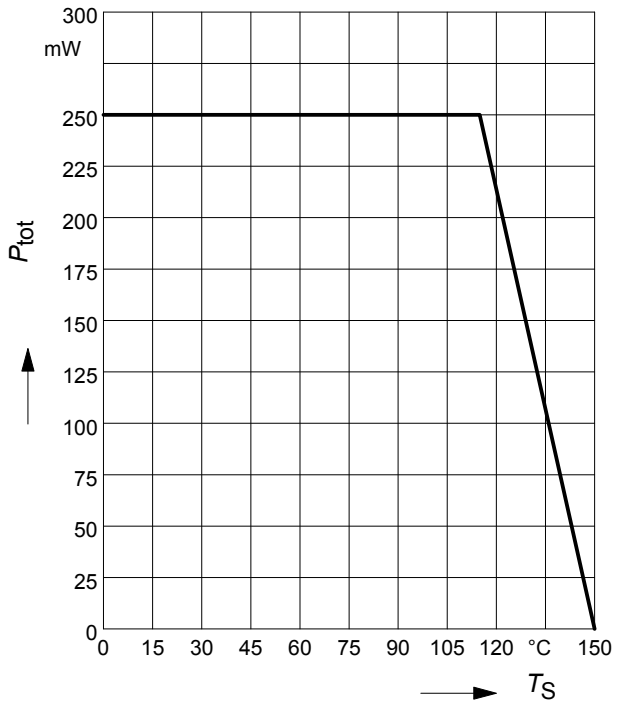
V_{CE} = 5V (common emitter configuration)



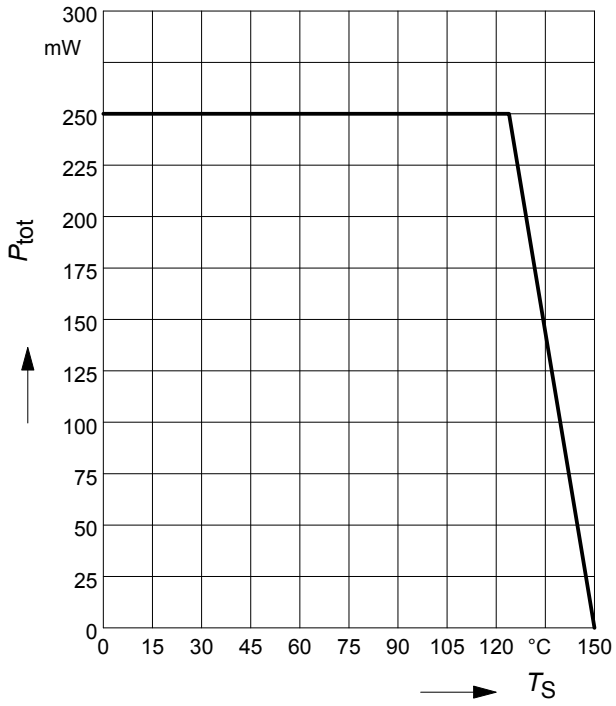
Total power dissipation $P_{tot} = f(T_S)$
BCR135



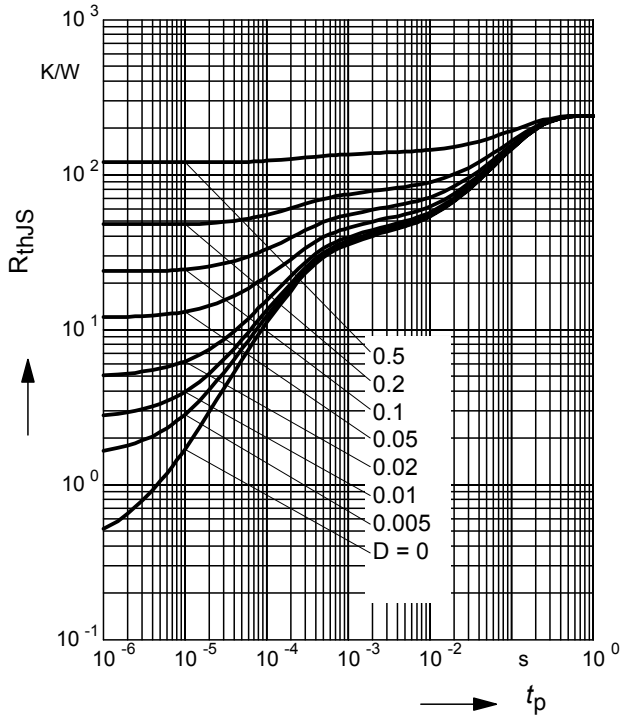
Total power dissipation $P_{tot} = f(T_S)$
BCR135S



Total power dissipation $P_{tot} = f(T_S)$
BCR135W



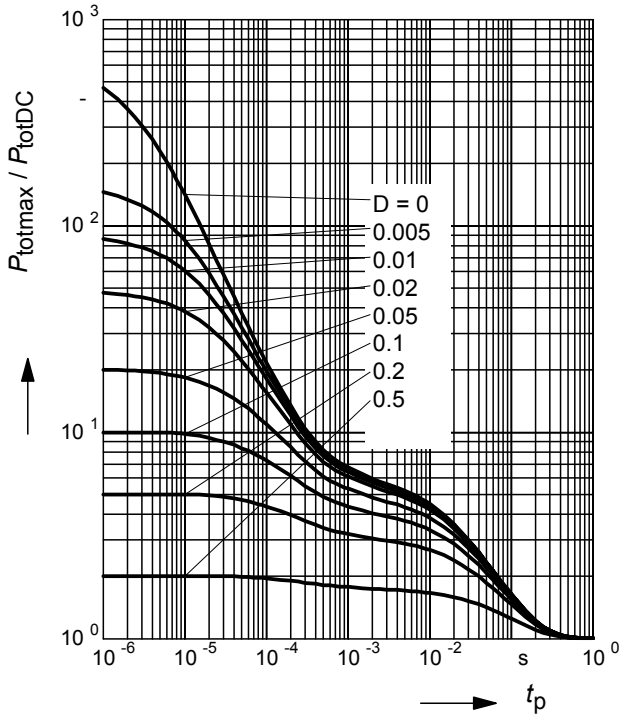
Permissible Pulse Load $R_{thJS} = f(t_p)$
BCR135



Permissible Pulse Load

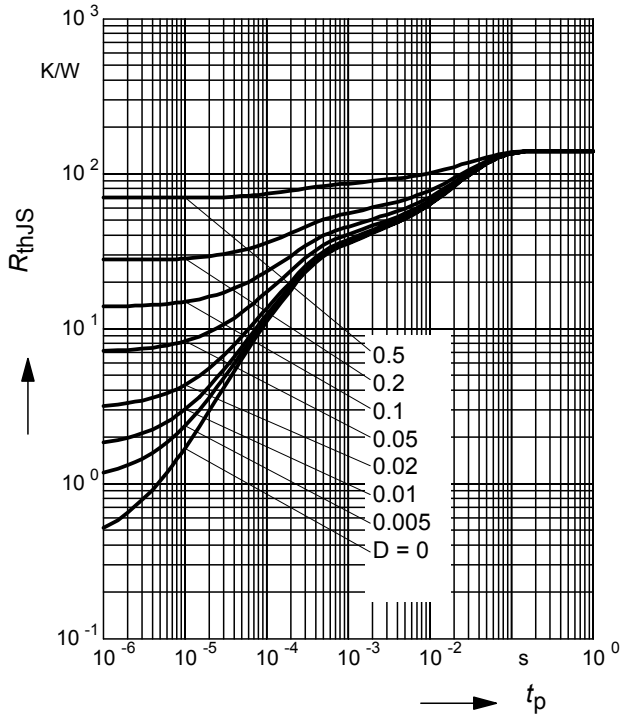
$P_{totmax}/P_{totDC} = f(t_p)$

BCR135



Permissible Puls Load $R_{thJS} = f(t_p)$

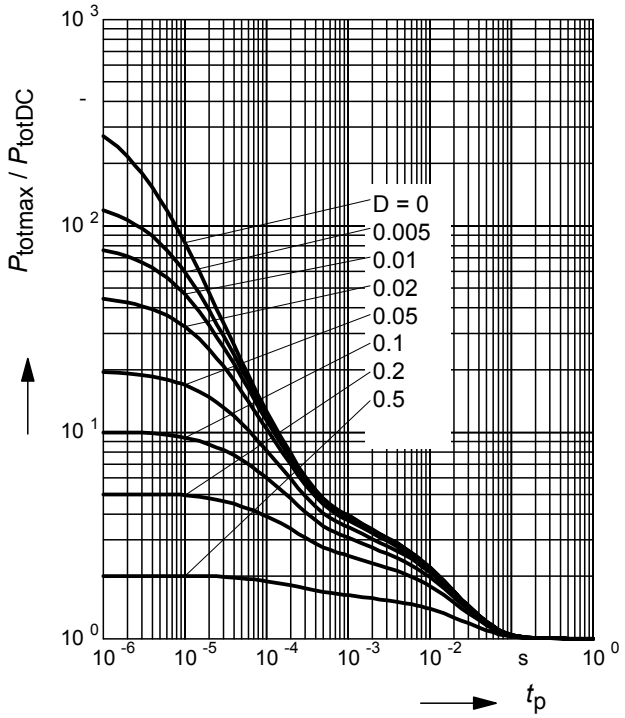
BCR135S



Permissible Pulse Load

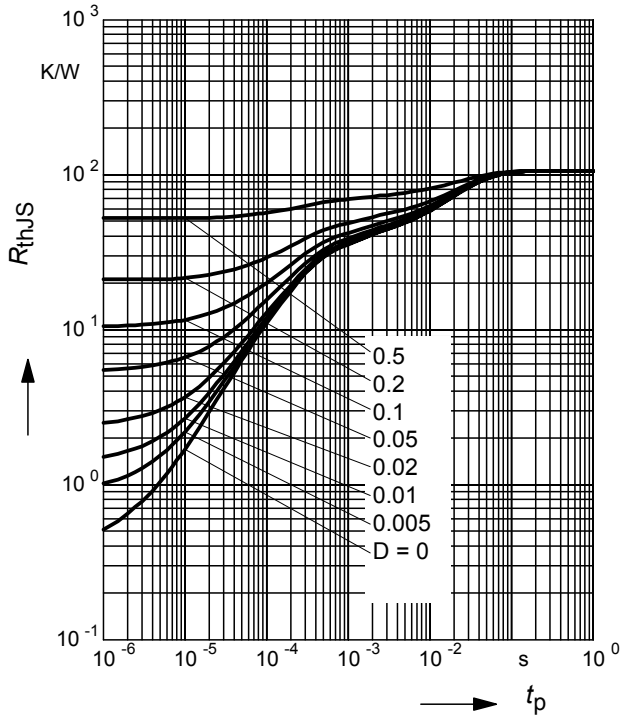
$P_{totmax}/P_{totDC} = f(t_p)$

BCR135S



Permissible Puls Load $R_{thJS} = f(t_p)$

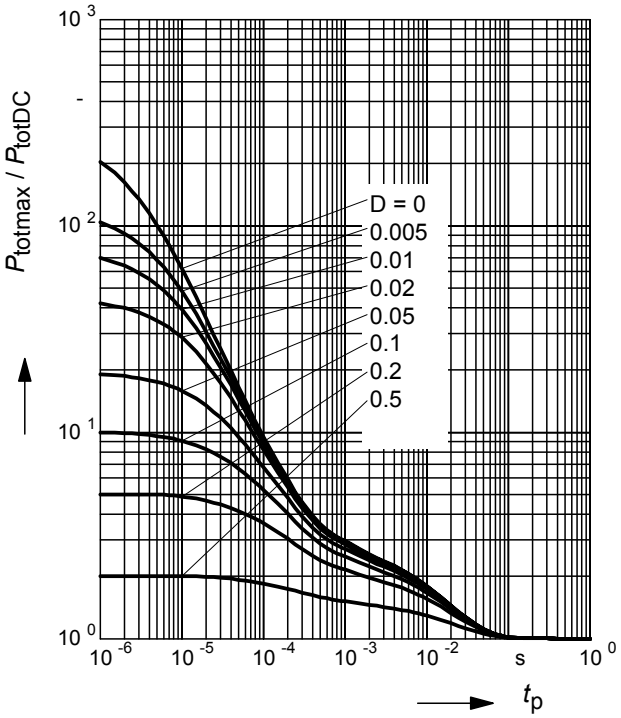
BCR135W



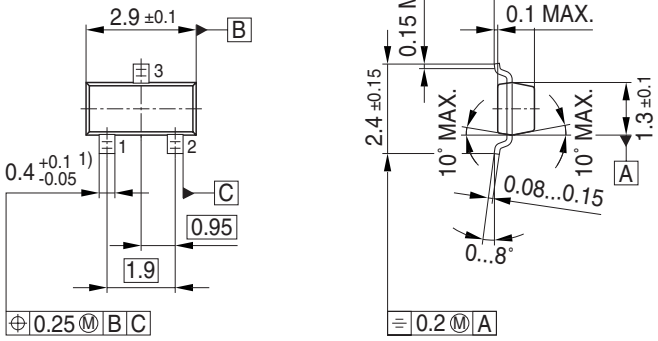
Permissible Pulse Load

$P_{totmax}/P_{totDC} = f(t_p)$

BCR135W

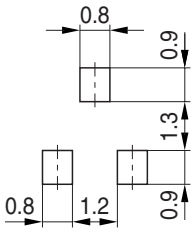


Package Outline

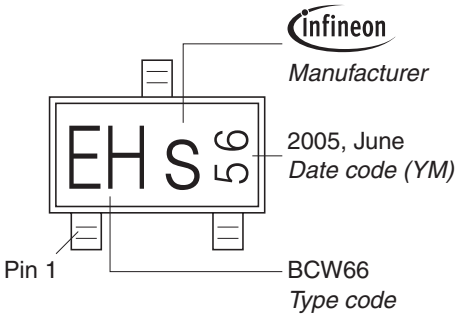


1) Lead width can be 0.6 max. in dambar area

Foot Print

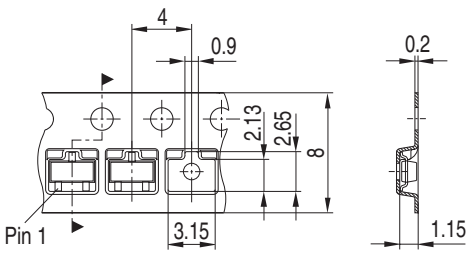


Marking Layout (Example)

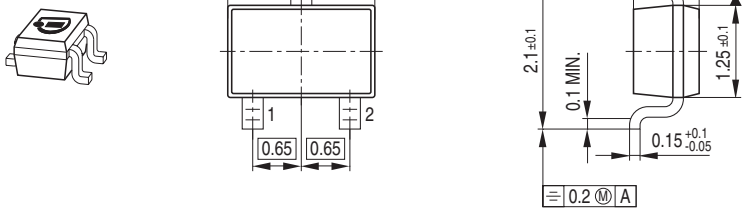


Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel
Reel ø330 mm = 10.000 Pieces/Reel



Package Outline



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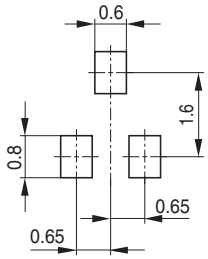
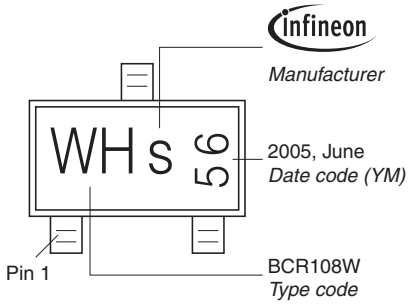


Marking Layout (Example)



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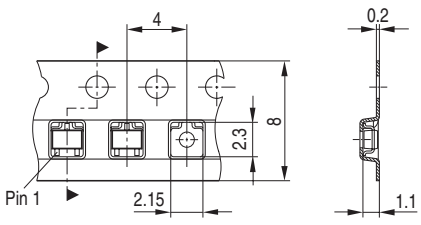
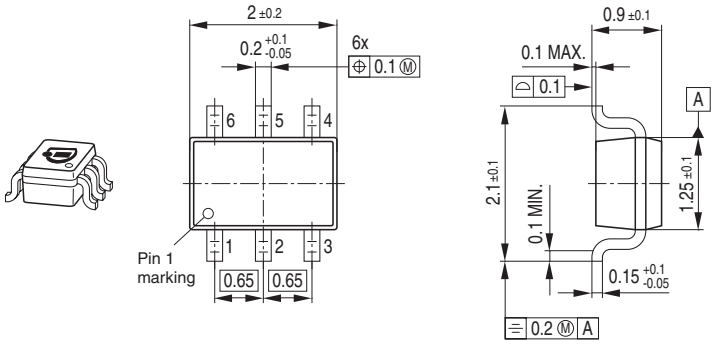


Package Outline



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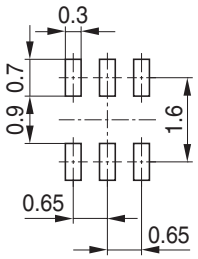
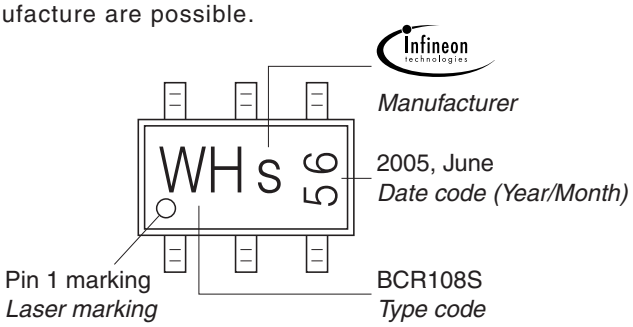


Marking Layout (Example)

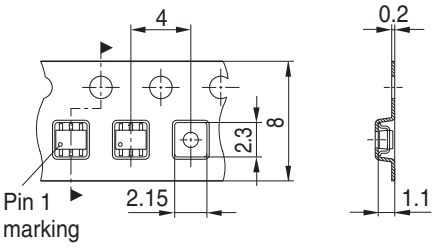
Small variations in positioning of
Date code, Type code and Manufacture are possible.



Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel
Reel ø330 mm = 10.000 Pieces/Reel

For symmetric types no defined Pin 1 orientation in reel.



Edition 2009-11-16

Published by
Infineon Technologies AG
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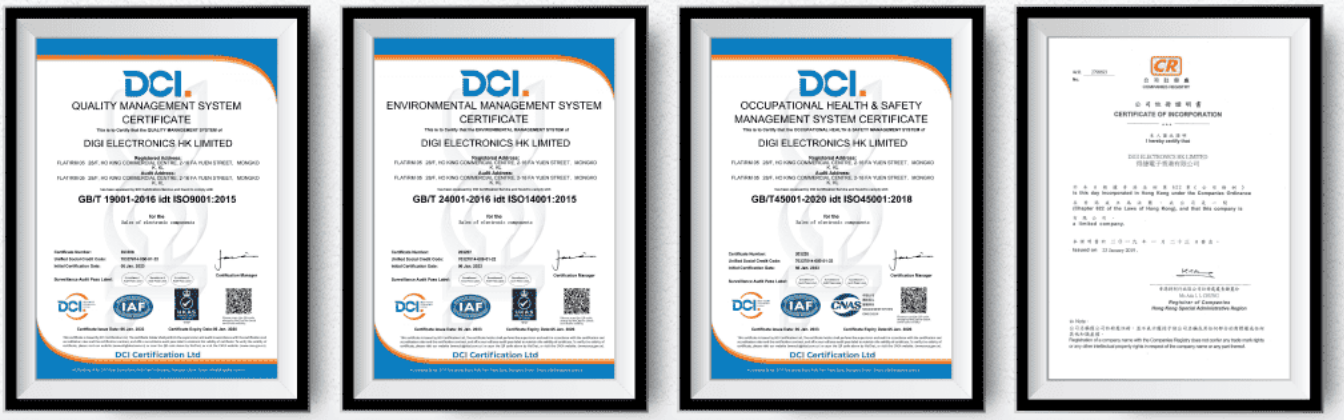

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